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## Additive Engineering and Surface Passivation for High Efficiency and Long-term Stability of $\alpha$ -FAPbI<sub>3</sub> Perovskite Solar Cells



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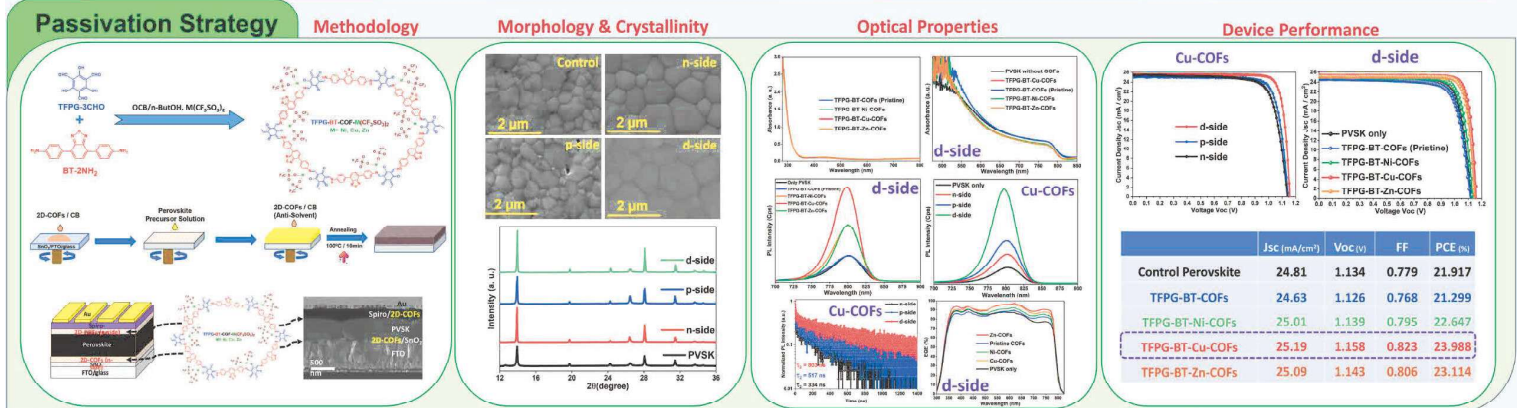
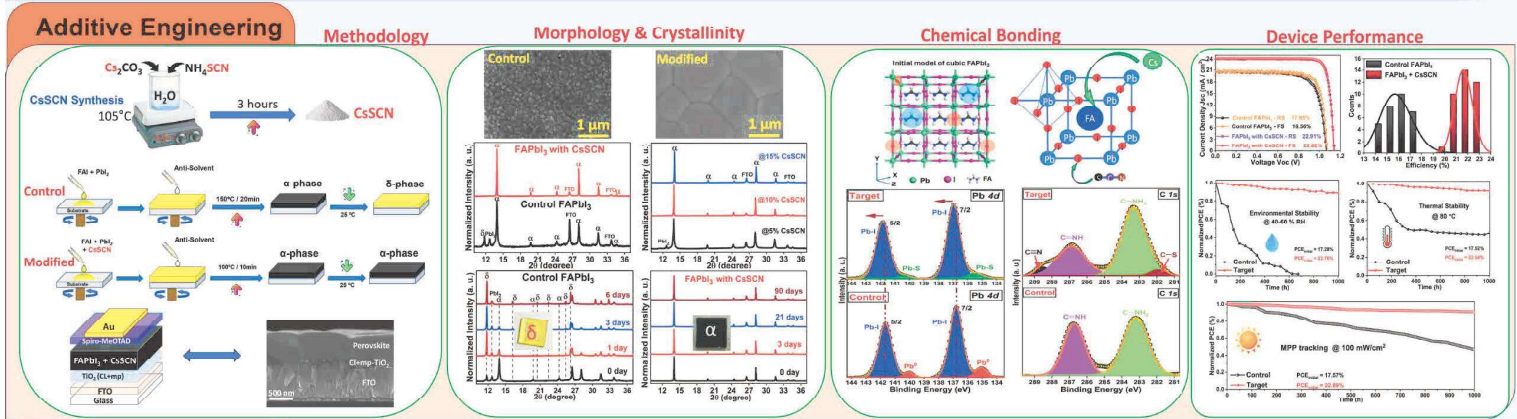
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### Introduction

Formamidinium lead triiodide (FAPbI<sub>3</sub>) is a promising semiconductor material for achieving efficient and thermally stable perovskite solar cells (PSCs). However, challenges such as phase instability and defect-related degradation hinder its performance and longevity. To address these issues, we introduce two synergistic approaches: **CsSCN** additive and dual-side surface passivation using **2D-COFs**. CsSCN, incorporated into the perovskite precursor solution, stabilizes the photoactive  $\alpha$ -phase of FAPbI<sub>3</sub>, as confirmed by XRD and MD simulations. This modification improves phase purity, increases grain size, enhances film uniformity, and reduces defects, resulting in a peak PCE of **22.91%** and operational stability exceeding 1000 hours under continuous illumination. Simultaneously, dual-side passivation with **(TFPG-BT-COFs-Cu(CF<sub>3</sub>-SO<sub>3</sub>)<sub>2</sub>)** addresses defect traps at the electron and hole interfaces. At the electron-transport layer, the ionic COFs interact with A-site cations (Cs, FA), compensating for defects and reducing nonradiative recombination. At the hole-transport layer, they alleviate lattice stresses and potential barriers, further enhancing stability and efficiency. This comprehensive strategy increased the output performance up to **23.99%** PCE. The combination of CsSCN additive and COF-based dual-side passivation presents a robust pathway to improve efficiency, stability, and durability of PSCs, paving the way for their widespread adoption in photovoltaic applications.



### Conclusion

In this work, a dual strategy to improve the efficiency and stability of FAPbI<sub>3</sub>-based PSCs. By incorporating CsSCN into the precursor solution,  $\alpha$ -FAPbI<sub>3</sub> is stabilized, enhancing grain size, film uniformity, and phase purity, leading to a PCE of 22.91% and over 1000 hours of operational stability. Additionally, dual-side passivation using 2D-COFs, (TFPG-BT-COFs-Cu(CF<sub>3</sub>-SO<sub>3</sub>)<sub>2</sub>), reduces defect traps and lattice stresses, increasing PCE to 23.99%. Together, these innovations significantly enhance PSC performance and durability, offering a robust pathway for their widespread photovoltaic applications.

### Acknowledgement

